

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	40	V
Average Rectified Output Current	lo	1	А
Repetitive peak Forward Current (Pulse Wave = 1 msec, Duty Cycle = 25%)	I <sub>FRM</sub>	5	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	14	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>0JA</sub>	135	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	R <sub>0JA</sub>	80	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

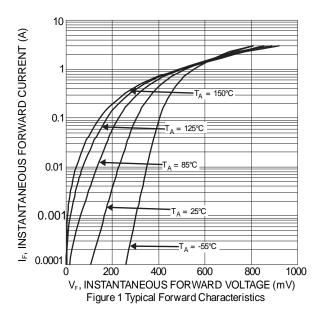
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

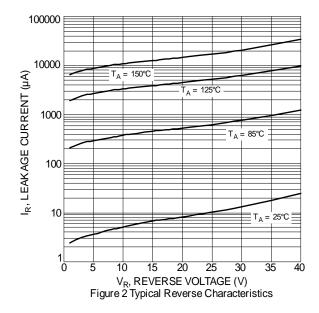
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	V <sub>F</sub>	-	0.41	0.46	V	I <sub>F</sub> = 0.5A, T <sub>J</sub> = +25°C
		-	0.51	0.56		I <sub>F</sub> = 1.0A, T <sub>J</sub> = +25°C
		-	0.49	П		$I_F = 1.0A, T_J = +125$ °C
Leakage Current (Note 7)	I <sub>R</sub>	-	-	15	uA I	V <sub>R</sub> = 10V, T <sub>J</sub> = +25°C
		-	-	75		V <sub>R</sub> = 40V, T <sub>J</sub> = +25°C
		-	9.5	-	mA	V <sub>R</sub> = 40V, T <sub>J</sub> = +125°C
Junction Capacitance	C <sub>T</sub>	-	35	-	pF	V <sub>R</sub> = 4V, f = 1.0MHz

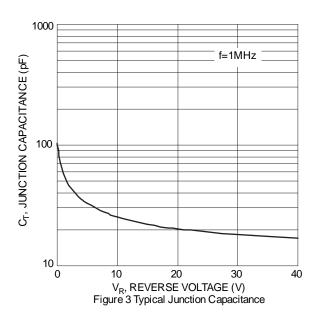
Notes:

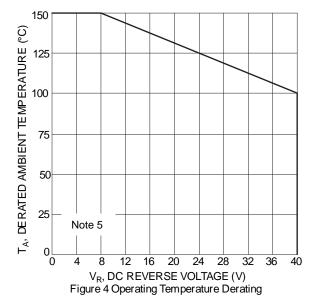
- Device mounted on FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
  Device mounted on FR-4 PCB, 2oz. 1 square inch Copper.
  Short duration pulse test used to minimize self-heating effect.









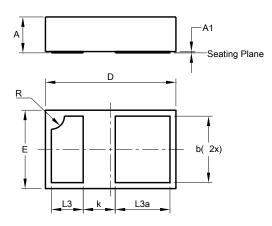




## **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

## X3-WLB1006-2

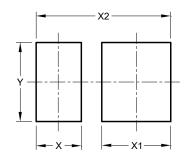


	X3-WLB1006-2				
Dim	Min	Max	Тур		
Α	0.25	0.30	0.275		
A1	0.00	0.01	-		
b	0.450	0.550	0.500		
D	0.95	1.05	1.000		
Е	0.55	0.65	0.600		
k	-	-	0.288		
L3	0.194	0.294	0.244		
L3a	0.350	0.450	0.400		
R	-	-	0.100		
All	All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

### X3-WLB1006-2



Dimensions	Value		
Dillielisions	(in mm)		
Х	0.332		
X1	0.507		
X2	0.989		
Y	0.579		



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